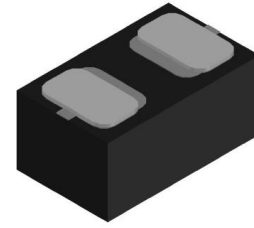
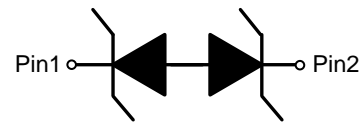


**ESD54211N**
**1-Line, Bi-directional, Transient Voltage Suppressors**
<http://www.sh-willsemi.com>
**Descriptions**

The ESD54211N is a bi-directional TVS (Transient Voltage Suppressor). It is specifically designed to protect sensitive electronic components which are connected to power lines, low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning.

The ESD54211N may be used to provide ESD protection up to  $\pm 30\text{kV}$  (contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 10A (8/20 $\mu\text{s}$ ) according to IEC61000-4-5.

The ESD54211N is available in WBFBP-02C-C package. Standard products are Pb-free and Halogen-free.


**WBFBP-02C-C**

**Circuit diagram**
**Features**

- Stand-off voltage:  $\pm 3.3\text{V}$  Max
- Transient protection for each line according to IEC61000-4-2 (ESD):  $\pm 30\text{kV}$  (contact discharge)  
IEC61000-4-4 (EFT): 40A (5/50ns)  
IEC61000-4-5 (surge): 10A (8/20 $\mu\text{s}$ )
- Capacitance:  $C_J = 17.5\text{pF}$  typ.
- Low leakage current:  $I_R < 1\text{nA}$  typ.
- Low clamping voltage:  $V_{CL} = 9\text{V}$  typ. @  $I_{PP} = 16\text{A}$  (TLP)
- Solid-state silicon technology



E = Device code

\* = Month code ( A~Z)

**Marking (Top View)**
**Applications**

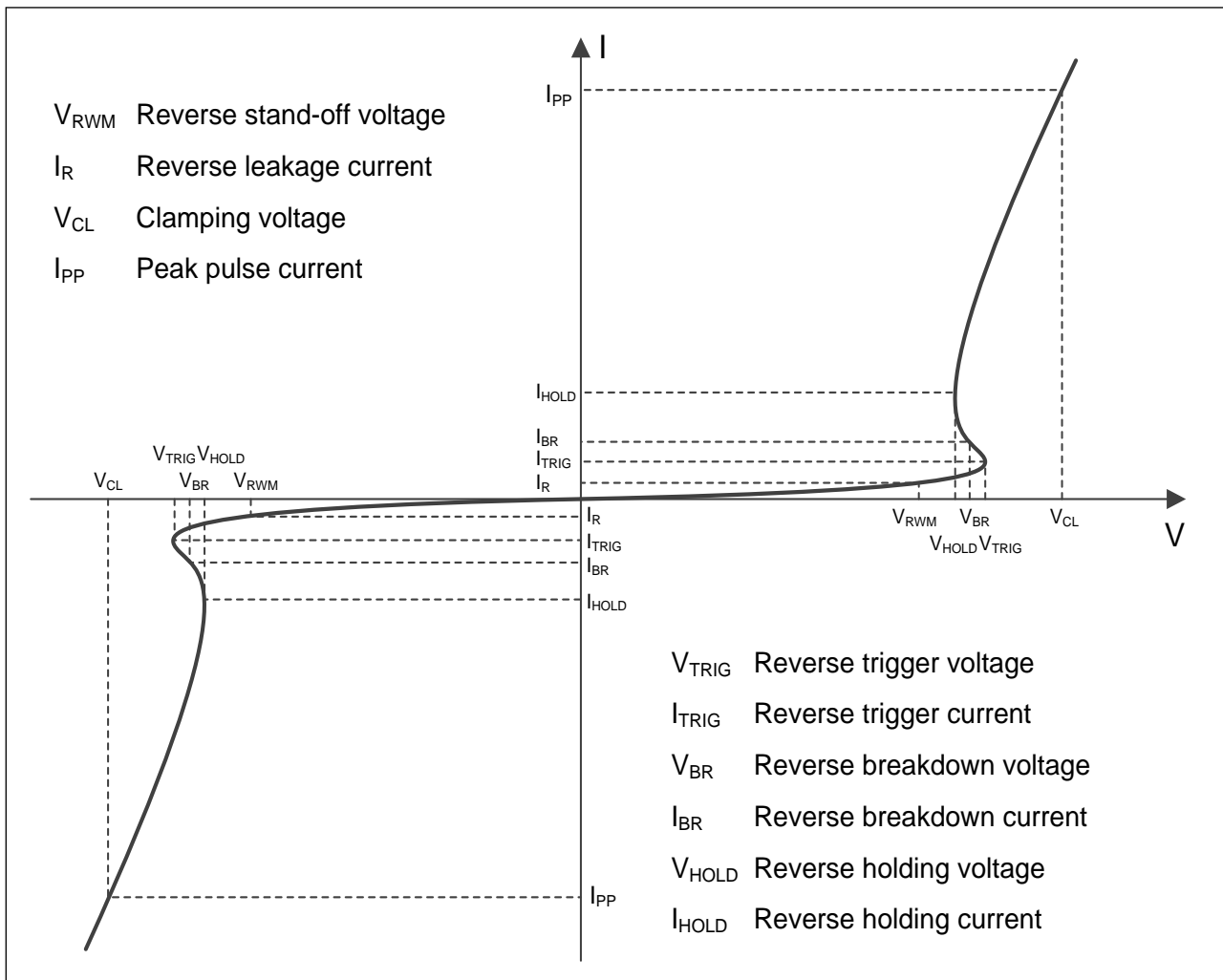
- Cellular handsets
- Computers and peripherals
- Microprocessors
- Power lines
- Portable Electronics
- Notebooks

**Order information**

Device	Package	Shipping
ESD54211N-2/TR	WBFBP-02C-C	10000/Tape&Reel

**Absolute maximum ratings**

Parameter	Symbol	Rating	Unit
Peak pulse power ( $t_p = 8/20\mu s$ )	$P_{pk}$	120	W
Peak pulse current ( $t_p = 8/20\mu s$ )	$I_{PP}$	10	A
ESD according to IEC61000-4-2 air discharge	$V_{ESD}$	$\pm 30$	kV
ESD according to IEC61000-4-2 contact discharge		$\pm 30$	
Junction temperature	$T_J$	125	$^{\circ}C$
Operating temperature	$T_{OP}$	-40~85	$^{\circ}C$
Lead temperature	$T_L$	260	$^{\circ}C$
Storage temperature	$T_{STG}$	-55~150	$^{\circ}C$

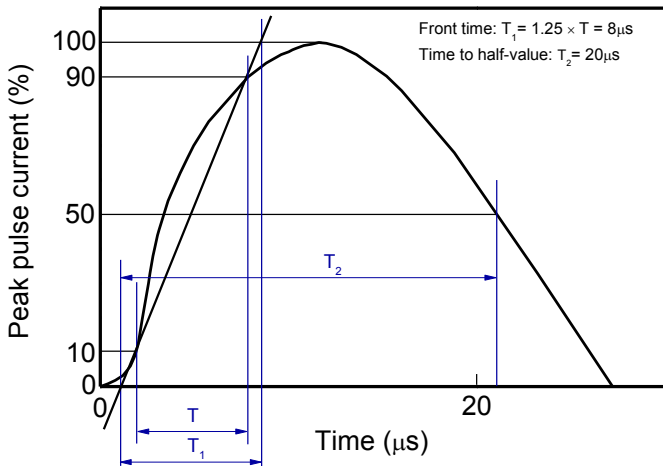
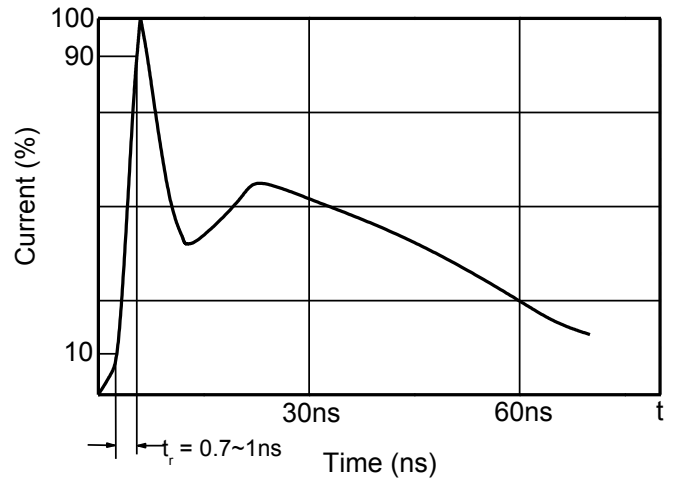
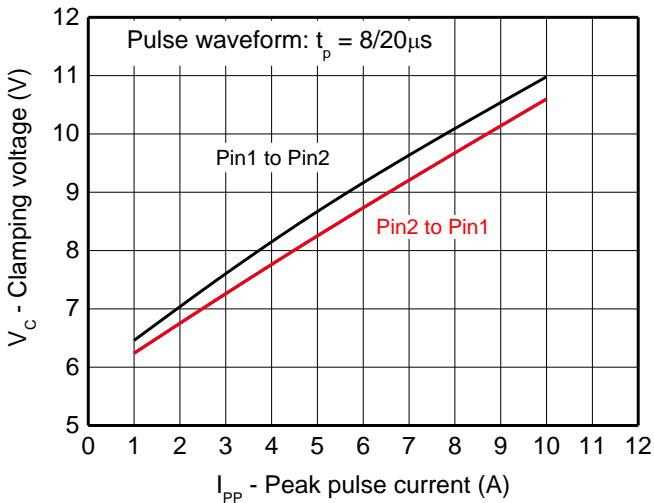
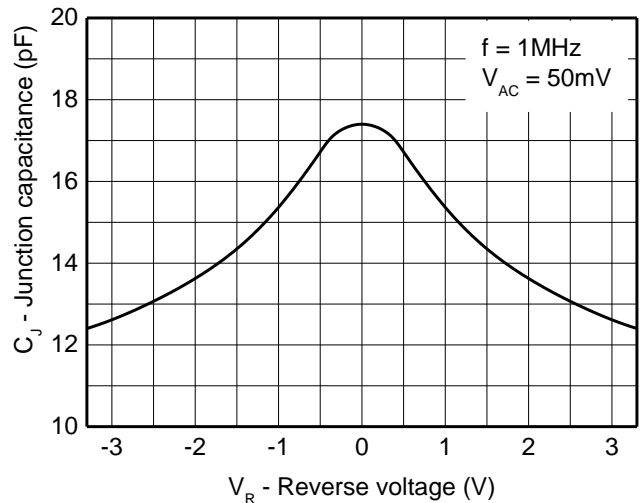
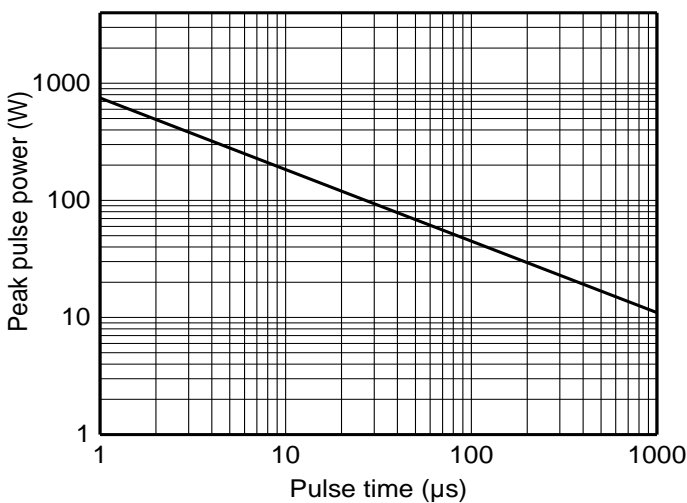
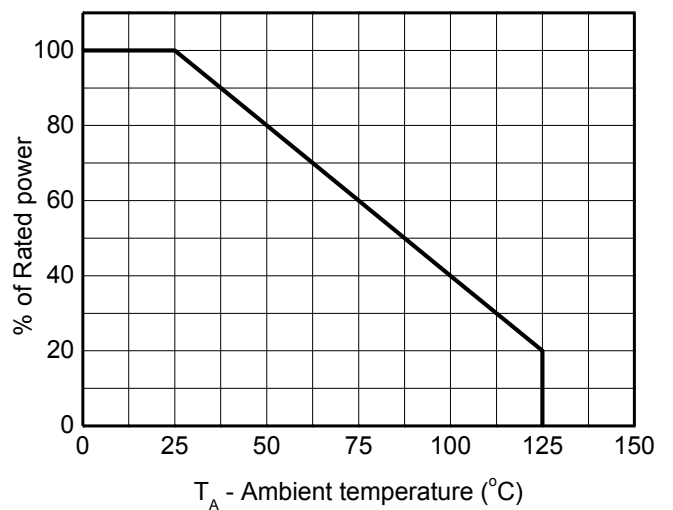
**Electrical characteristics ( $T_A=25^{\circ}C$ , unless otherwise noted)**

**Definitions of electrical characteristics**

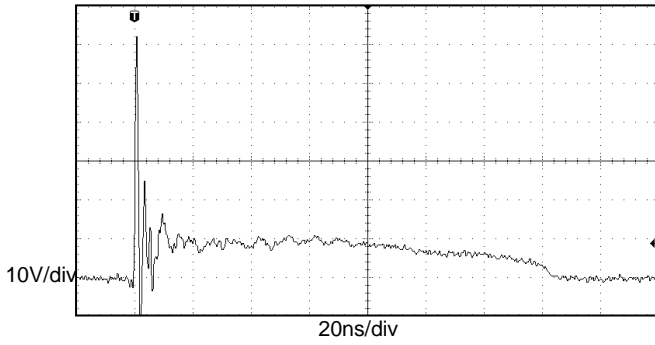
**Electrical characteristics (T<sub>A</sub>=25 °C, unless otherwise noted)**

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V <sub>RWM</sub>				±3.3	V
Reverse leakage current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3V		<1	100	nA
Reverse breakdown voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA	4.2			V
Reverse holding voltage	V <sub>HOLD</sub>	I <sub>HOLD</sub> = 50mA	4.1			V
Clamping voltage <sup>1)</sup>	V <sub>CL</sub>	I <sub>PP</sub> = 16A, t <sub>p</sub> = 100ns		9		V
Clamping voltage <sup>2)</sup>	V <sub>CL</sub>	V <sub>ESD</sub> = 8kV		10		V
Clamping voltage <sup>3)</sup>	V <sub>CL</sub>	I <sub>PP</sub> = 1A, t <sub>p</sub> = 8/20μs			7.5	V
		I <sub>PP</sub> = 5A, t <sub>p</sub> = 8/20μs			10	V
		I <sub>PP</sub> = 10A, t <sub>p</sub> = 8/20μs			12	V
Dynamic resistance <sup>1)</sup>	R <sub>DYN</sub>			0.25		Ω
Junction capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHz		17.5	22	pF
		V <sub>R</sub> = 3.3V, f = 1MHz		12.5	16	pF

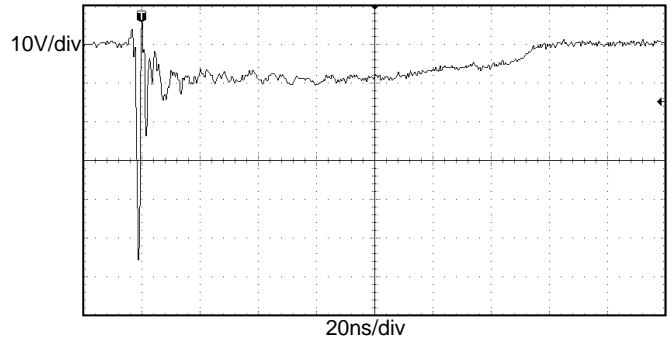
**Notes:**

- 1) TLP parameter: Z<sub>0</sub> = 50Ω, t<sub>p</sub> = 100ns, t<sub>r</sub> = 2ns, averaging window from 60ns to 80ns. R<sub>DYN</sub> is calculated from 4A to 16A.
- 2) Contact discharge mode, according to IEC61000-4-2.
- 3) Non-repetitive current pulse, according to IEC61000-4-5.

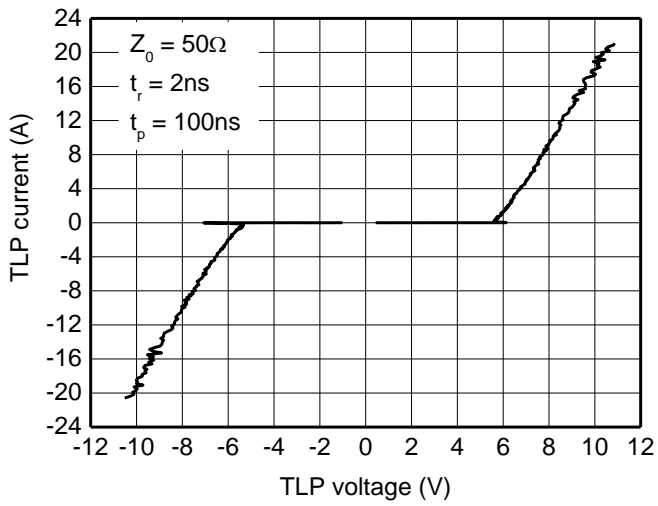
**Typical characteristics ( $T_A=25^\circ\text{C}$ , unless otherwise noted)**

**8/20 $\mu\text{s}$  waveform per IEC61000-4-5**

**Contact discharge current waveform per IEC61000-4-2**

**Clamping voltage vs. Peak pulse current**

**Capacitance vs. Reverse voltage**

**Non-repetitive peak pulse power vs. Pulse time**

**Power derating vs. Ambient temperature**

**Typical characteristics ( $T_A=25^\circ\text{C}$ , unless otherwise noted)**


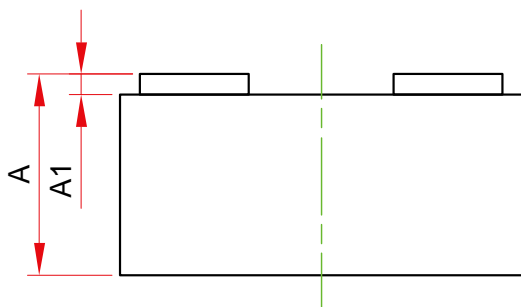
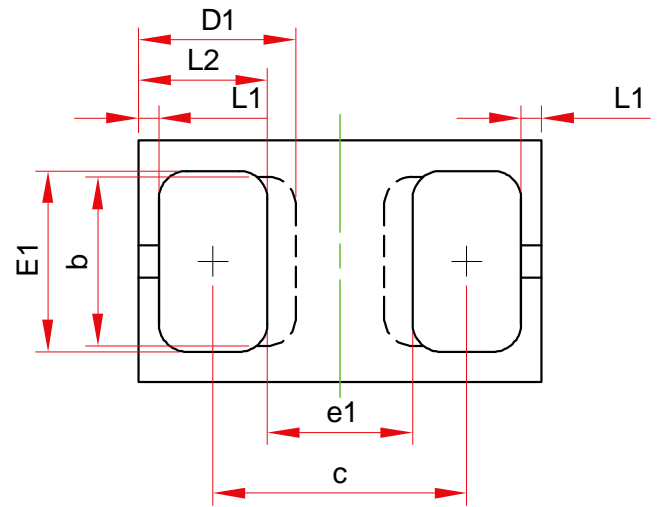
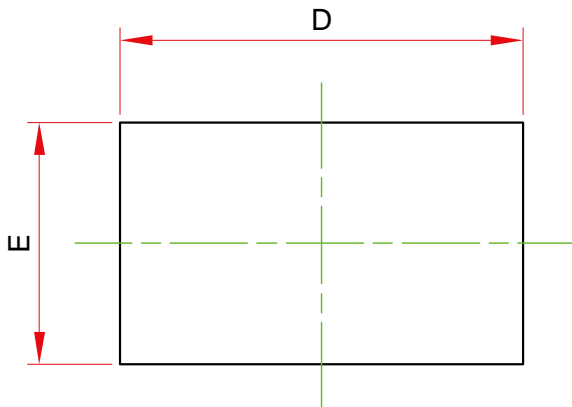
**ESD clamping**  
 (+8kV contact discharge per IEC61000-4-2)



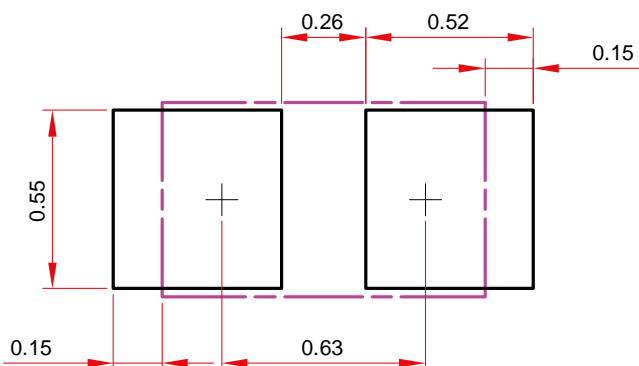
**ESD clamping**  
 (-8kV contact discharge per IEC61000-4-2)



**TLP Measurement**

**Package outline dimensions**
**WBFBP-02C-C**


Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.450	--	0.550
A1	0.010	--	0.090
D	0.950	--	1.050
E	0.550	--	0.650
D1	0.390 Ref.		
E1	0.400	--	0.500
b	0.420 Ref.		
c	0.580	--	0.680
e1	0.360 Ref.		
L1	0.050 Ref.		
L2	0.270	--	0.370

**Recommend land pattern (Unit: mm)**

**Notes:**

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

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